



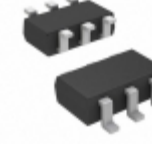




	<h2>SQ3442EV-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SQ3442EV-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 4.3A 6TSOP</p> <p>Datenblätter:  SQ3442EV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 36610 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SQ3442EV-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 20V 4.3A 6TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	36610 pcs Stock
detaillierte Beschreibung	N-Channel 20V 4.3A (Tc) 1.7W (Tc) Surface Mount 6-
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.3A (Tc)
Rds On (Max) @ Id, Vgs	55 mOhm @ 4A, 4.5V
VGS (th) (Max) @ Id	1.6V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	405pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±8V
Verpackung	Original-Reel®
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SQ3442EV-T1-GE3DKR

SQ3442EV-T1-GE3 ist neu im Original, Suche SQ3442EV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SQ3442EV-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SQ3442EV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SQ3427EEV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 5.5A 6TSOP</p>	 <p>SQ3456BEV-T1_GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 7.8A 6TSOP</p>	 <p>SQ3427EV-T1_GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 6TSOP</p>	 <p>SQ3456BEV-T1_GE3 Vishay / Siliconix MOSFET N-CH 30V 7.8A 6TSOP</p>
 <p>SQ3427EEV-T1-GE3 Vishay / Siliconix MOSFET P-CH 60V 5.5A 6TSOP</p>	 <p>SQ3427EV-T1-GE3 Vishay Precision Group SQ3427EV-T1-GE3 VISHAY</p>	 <p>SQ3456BEV-T1-GE3 VISHAY SQ3456BEV-T1-GE3 VISHAY</p>	 <p>SQ3442EV-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 4.3A 6TSOP</p>

heiße Teile

Mehr

AP2127N-1.5TRG1	BH30MA3WHFV-TR	FQPF4N80C	GRM0225C1E7R7WDAEL	GRM1555C1H4R8WZ01D
IRF9640PBF	LDA10-24S12	LMV331IDCKR	LT3489EMS8E#TRPBF	LTC2632ACTS8-HI12#TRPBF
MAX6348UR46-T	NJU3718G-TE1	PIC16F1824-E/ST	QM75E2Y-24	REF3120AIDBZRG4
RSR010N10FHA	SC414450VV	SN74AUC1GU04DCKR	SQ3410EV-T1-GE3	SQ3418EEV-T1-GE3
SQ3418EEV-T1-GE3	SQ3418EV-T1-GE3	SQ3419EEV-T1-GE3	SQ3419EEV-T1-GE3	SQ3419EV-T1-GE3
SQ3425EV-T1-GE3	SQ3426EEV-T1-GE3	D SQ3426EEV-T1-GE3	SQ3426EV-T1-GE3	SQ3427EEV-T1-GE3
SQ3427EEV-T1-GE3	D SQ3427EV	SQ3427EV-T1-GE3	SQ3442EV-T1-GE3	SQ3456BES-T1-GE3
SQ3456BEV-T1-GE3	SQ3456EV-T1-GE3	SQ3457EV-T1-GE3	SQ3457KGD	SQ3460EV-T1-GE3
SQ3461EV-T1-GE3	SQ3469EV-T1-GE3	SQ3481EV-T1-GE3	D SQ3985EV-T1-GE3	SQ3987EV-T1-GE3
SQ3989EV-T1-GE3	SSM3J168F	TDA8035HN	TLP185GB	TPS74201KTWR

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited